

# HMBT3904U

TRANSISTOR (NPN)

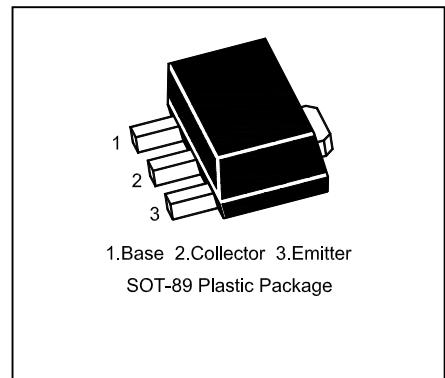
## FEATURES

- Compliment to 2N3906U
- Low current
- Low voltage

## MARKING: 1A

**MAXIMUM RATINGS ( $T_a=25^\circ\text{C}$  unless otherwise noted)**

Symbol	Parameter	Value	Unit
$V_{CBO}$	Collector-Base Voltage	60	V
$V_{CEO}$	Collector-Emitter Voltage	40	V
$V_{EBO}$	Emitter-Base Voltage	6	V
$I_c$	Collector Current -Continuous	0.2	A
$P_c$	Collector Power Dissipation	0.5	W
$T_J$	Junction Temperature	150	$^\circ\text{C}$
$T_{stg}$	Storage Temperature	-55~150	$^\circ\text{C}$

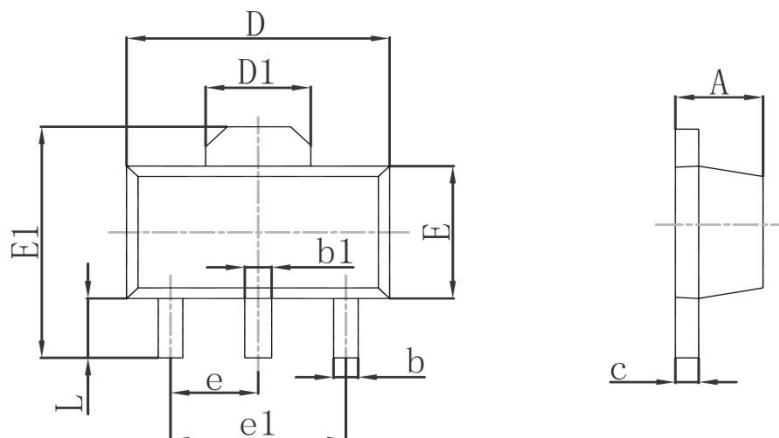


**ELECTRICAL CHARACTERISTICS ( $T_a=25^\circ\text{C}$  unless otherwise specified)**

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
<b>Collector-base breakdown voltage</b>	$V_{(BR)CBO}$	$I_C=10\mu\text{A}, I_E=0$	60			V
<b>Collector-emitter breakdown voltage</b>	$V_{(BR)CEO}$	$I_C=1\text{mA}, I_B=0$	40			V
<b>Emitter-base breakdown voltage</b>	$V_{(BR)EBO}$	$I_E=10\mu\text{A}, I_C=0$	6			V
<b>Collector cut-off current</b>	$I_{CBO}$	$V_{CB}=30\text{V}, I_E=0$			0.05	$\mu\text{A}$
<b>Emitter cut-off current</b>	$I_{EBO}$	$V_{EB}=6\text{V}, I_C=0$			0.05	$\mu\text{A}$
<b>Collector ut-off current</b>	$I_{CEX}$	$V_{CE}=30\text{V}, V_{BE(\text{off})}=3\text{V}$			0.05	$\mu\text{A}$
<b>DC current gain</b>	$h_{FE(1)}$	$V_{CE}=1\text{V}, I_C=0.1\text{mA}$	60			
	$h_{FE(2)}$	$V_{CE}=1\text{V}, I_C=1\text{mA}$	80			
	$h_{FE(3)}$	$V_{CE}=1\text{V}, I_C=10\text{mA}$	100		300	
	$h_{FE(4)}$	$V_{CE}=1\text{V}, I_C=50\text{mA}$	60			
	$h_{FE(5)}$	$V_{CE}=1\text{V}, I_C=100\text{mA}$	30			
<b>Collector-emitter saturation voltage</b>	$V_{CE(\text{sat})1}$	$I_C=10\text{mA}, I_B=1\text{mA}$			0.2	V
	$V_{CE(\text{sat})2}$	$I_C=50\text{mA}, I_B=5\text{mA}$			0.3	V
<b>Base-emitter saturation voltage</b>	$V_{BE(\text{sat})1}$	$I_C=10\text{mA}, I_B=1\text{mA}$	0.65		0.85	V
	$V_{BE(\text{sat})2}$	$I_C=50\text{mA}, I_B=5\text{mA}$			0.95	V
<b>Transition frequency</b>	$f_T$	$V_{CE}=20\text{V}, I_C=10\text{mA}, f=100\text{MHz}$	300			MHz
<b>Collector capacitance</b>	$C_c$	$V_{CB}=5\text{V}, I_E=0, f=1\text{MHz}$			4	pF
<b>Emitter capacitance</b>	$C_e$	$V_{EB}=0.5\text{V}, I_C=0, f=1\text{MHz}$			8	pF
<b>Noise figure</b>	NF	$V_{CE}=5\text{V}, I_C=0.1\text{mA}, f=10\text{Hz}-15.7\text{kHz}, R_S=1\text{K}\Omega$			5	dB
<b>Delay time</b>	$t_d$	$I_C=10\text{mA}, I_{B1}=-I_{B2}=1\text{mA}$			35	ns
<b>Rise time</b>	$t_r$				35	ns
<b>Storage time</b>	$t_s$				200	ns
<b>Fall time</b>	$t_f$				50	ns

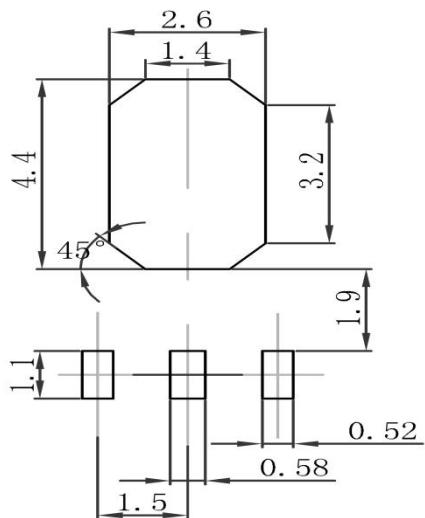
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## SOT-89 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	1.400	1.600	0.055	0.063
b	0.320	0.520	0.013	0.020
b1	0.400	0.580	0.016	0.023
c	0.350	0.440	0.014	0.017
D	4.400	4.600	0.173	0.181
D1	1.550REF		0.061REF	
E	2.300	2.600	0.091	0.102
E1	3.940	4.250	0.155	0.167
e	1.500TYP		0.060TYP	
e1	3.000TYP		0.118TYP	
L	0.900	1.200	0.035	0.047

## SOT-89 Suggested Pad Layout

**Note:**

1. Controlling dimension: in millimeters
2. General tolerance:  $\pm 0.05\text{mm}$
3. The pad layout is for reference purposes only